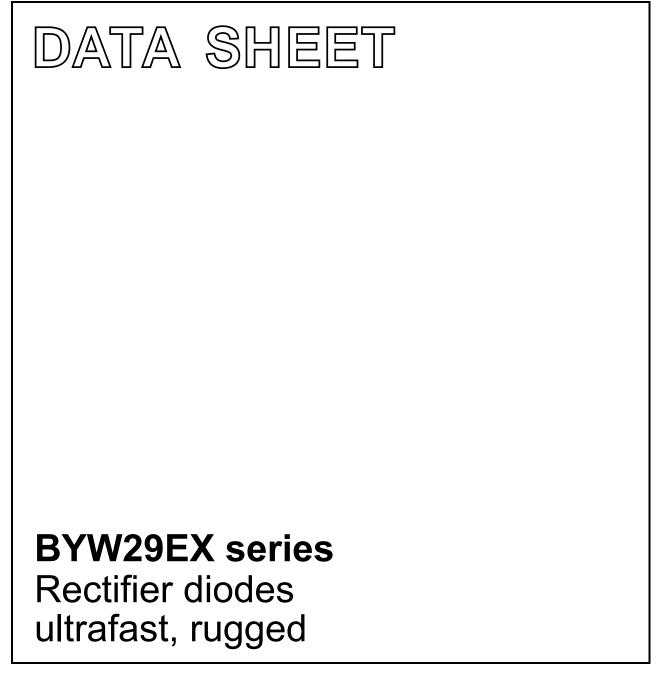
DISCRETE SEMICONDUCTORS



Product specification

September 2018



#### **Rectifier diodes** ultrafast, rugged

#### **GENERAL DESCRIPTION**

Glass passivated epitaxial rectifier diodes in a full pack plastic envelope, featuring low forward voltage drop, ultra-fast recovery times, soft recovery characteristic and guaranteed reverse surge and ESD capability. They are intended for use in switched mode power supplies and high frequency circuits in general where low conduction and switching losses are essential.

DESCRIPTION

#### **PINNING - SOD113**

LIMITING VALUES

PIN

 $\underline{\mathsf{T}}_{\mathsf{stg}}$ 

T

# mb TO-220F (SOD113)

**PIN CONFIGURATION** 

QUICK REFERENCE DATA

PARAMETER

Forward voltage

Forward current

voltage

current

Repetitive peak reverse

Reverse recovery time

Repetitive peak reverse

SYMBOL

 $V_{\text{RRM}}$ 

VF

t<sub>rr</sub>`

 $\mathbf{I}_{\mathsf{F}(\mathsf{AV})}$ 

I<sub>RRM</sub>

#### SYMBOL

BYW29EX-

-40

# К — А — А

001aaa020

150

150

MAX.

150

150

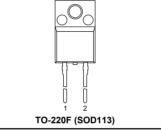
0.895

8

25

0.2

#### 1 cathode 2 anode isolated case



Limiting values in accordance with the Absolute Maximum System (IEC 134).								
	SYMBOL	PARAMETER	CONDITIONS	MIN.	MA	UNIT		
	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	Repetitive peak reverse voltage Crest working reverse voltage Continuous reverse voltage		- - -	<b>-150</b> 150 150 150	<b>-200</b> 200 200 200	> > >	
	I <sub>F(AV)</sub>	Average forward current <sup>1</sup>	square wave; $\delta = 0.5$ ; $T_{hs} \le 106 \degree C$ sinusoidal; $a = 1.57$ ; $T_{hs} \le 109 \degree C$	-		3	A	
	I <sub>F(RMS)</sub> I <sub>FRM</sub>	RMS forward current Repetitive peak forward current		-	7.3 11.3 16		A A	
	I <sub>FSM</sub>	Non-repetitive peak forward current	t = 10  ms t = 8.3  ms sinusoidal; with reapplied	-		0 8	A A	
	l²t I <sub>RRM</sub> I <sub>RSM</sub>	I <sup>2</sup> t for fusing Repetitive peak reverse current Non-repetitive peak reverse	V <sub>RWM(max)</sub> t = 10 ms	- - -	32 0.2 0.2		A <sup>2</sup> s A A	

#### 1 Neglecting switching and reverse current losses

Operating junction temperature

Storage temperature

current

°C C

**BYW29EX** series

MAX.

200

200

0.895

8

25

0.2

UNIT

V

V

А

ns

А

# Rectifier diodes ultrafast, rugged

## **BYW29EX series**

### **ESD LIMITING VALUE**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Vc	Electrostatic discharge capacitor voltage	Human body model; C = 250 pF; R = 1.5 kΩ	-	8	kV

### **ISOLATION LIMITING VALUE & CHARACTERISTIC**

 $T_{hs} = 25$  °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>isol</sub>	R.M.S. isolation voltage from both terminals to external heatsink	f = 50-60 Hz; sinusoidal waveform; R.H. $\leq$ 65% ; clean and dustfree	-		2500	V
C <sub>isol</sub>	Capacitance from both terminals to external heatsink	f = 1 MHz	-	10	-	pF

#### THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R <sub>th j-hs</sub> R <sub>th j-a</sub>	heatsink	with heatsink compound without heatsink compound in free air	-	- - 55	5.5 7.2 -	K/W K/W K/W

#### STATIC CHARACTERISTICS

 $T_i = 25$  °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>F</sub>	Forward voltage	I <sub>F</sub> = 8 A; T <sub>j</sub> = 150°C	-	0.80	0.895	V
		$I_{\rm F} = 8  {\rm A}$	-	0.92	1.05	V
	Reverse current	I <sub>F</sub> = 20 A V <sub>R</sub> = V <sub>RWM</sub> ; T <sub>i</sub> = 100 °C	-	0.2	1.3 0.6	v mA
R		$V_{R} = V_{RWM}$	-	2	10	μA

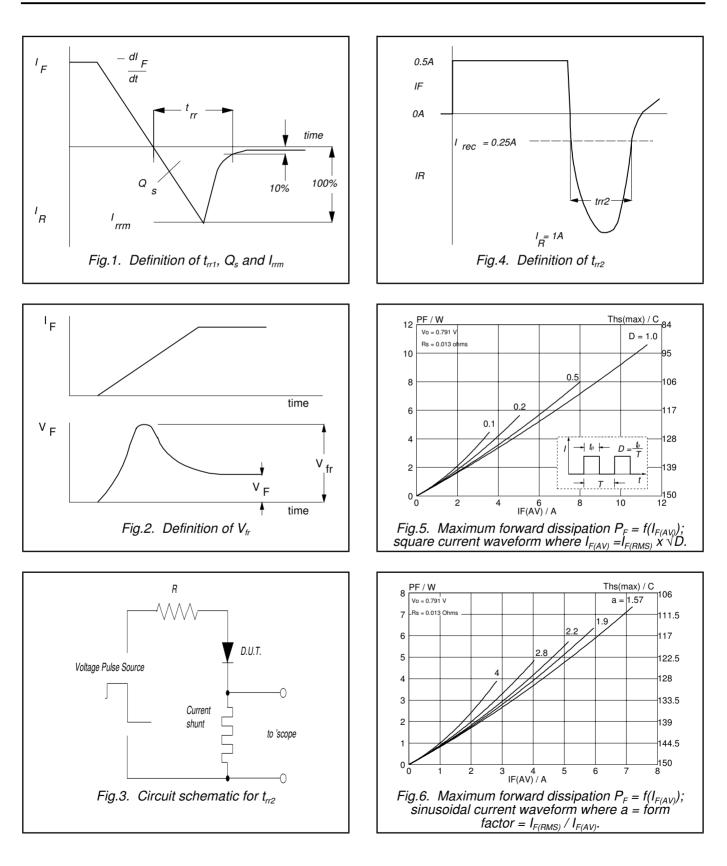
#### **DYNAMIC CHARACTERISTICS**

 $T_i = 25$  °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Q <sub>s</sub> t <sub>rr1</sub>	Reverse recovery charge Reverse recovery time	$I_F = 2 \text{ A}; V_R \ge 30 \text{ V}; -dI_F/dt = 20 \text{ A}/\mu\text{s}$ $I_F = 1 \text{ A}; V_R \ge 30 \text{ V};$ $-dI_F/dt = 100 \text{ A}/\mu\text{s}$		4 20	11 25	nC ns
t <sub>rr2</sub> V <sub>fr</sub>	Reverse recovery time Forward recovery voltage	$I_{F} = 0.5 \text{ A to } I_{R} = 1 \text{ A}; I_{rec} = 0.25 \text{ A}$ $I_{F} = 1 \text{ A}; dI_{F}/dt = 10 \text{ A}/\mu\text{s}$	-	15 1	20 -	ns V

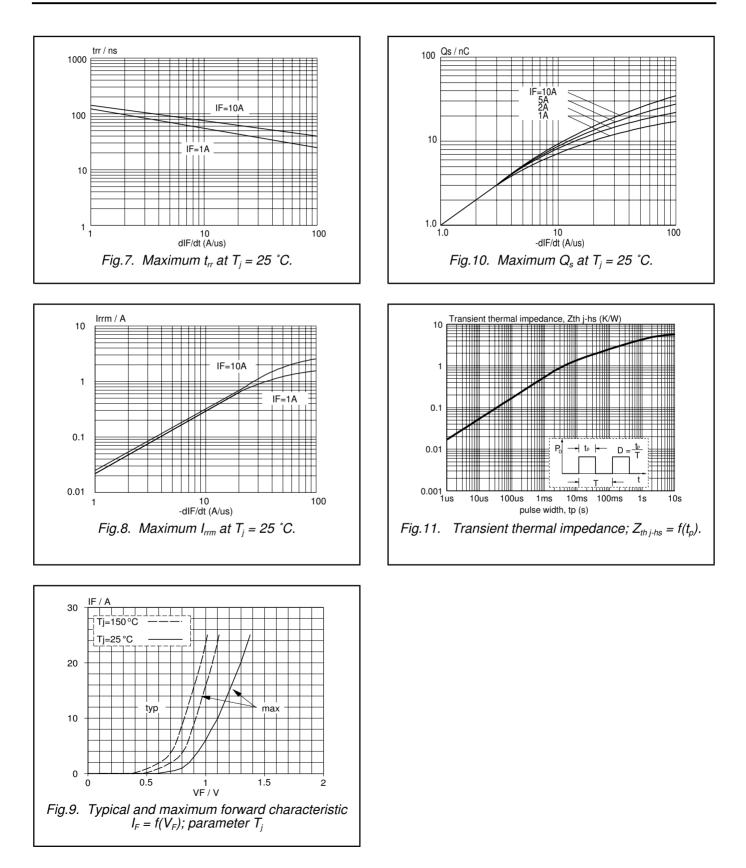
# Rectifier diodes ultrafast, rugged

# **BYW29EX** series



**BYW29EX** series

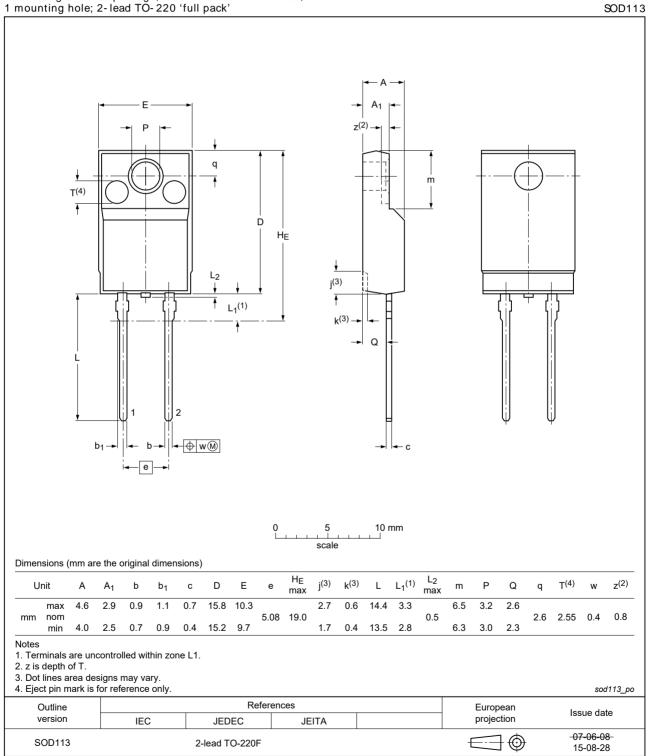
# Rectifier diodes ultrafast, rugged



### **BYW29EX** series

#### **MECHANICAL DATA**

Plastic single- ended package; isolated heatsink mounted; 1 mounting hole; 2- lead TO- 220 'full pack'



### Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <u>http://www.ween-semi.com</u>.

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